

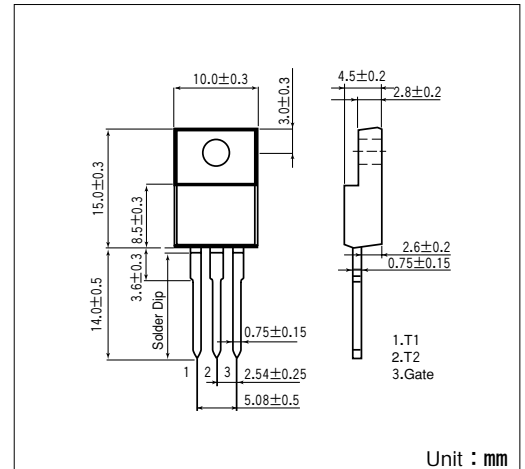
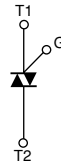
TRIAC (ISOLATED TYPE)

TMG16C60F

UL:E76102 (M)

TMG16C40/60F are isolated mold triac suitable for wide range of applications like copier, microwave oven, solid state switch, motor control, light and heater control.

- $I_T(\text{RMS})$ 16A
- High surge capability 170A
- Full molded isolated type



Maximum Ratings

($T_j=25^\circ\text{C}$ unless otherwise specified)

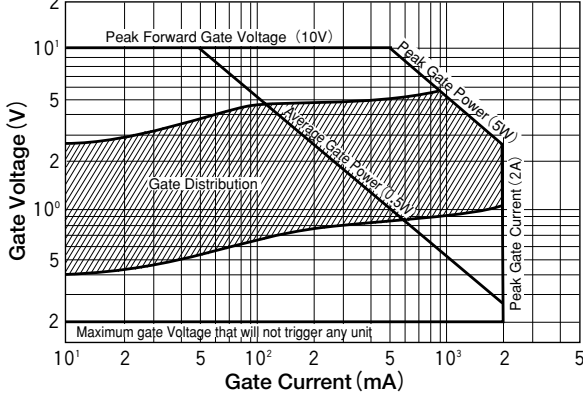
Symbol	Item	Ratings		Unit
		TMG16C40F	TMG16C60F	
V_{DRM}	Repetitive Peak Off-State Voltage	400	600	V

Symbol	Item	Conditions	Ratings	Unit
$I_{\text{T(RMS)}}$	R.M.S. On-State Current	$T_c=68^\circ\text{C}$	16	A
I_{TSM}	Surge On-State Current	One cycle, 50Hz/60Hz, peak, non-repetitive	155/170	A
I^2t	I^2t		120	A^2S
P_{GM}	Peak Gate Power Dissipation		5	W
$P_{\text{G(AV)}}$	Average Gate Power Dissipation		0.5	W
I_{GM}	Peak Gate Current		2	A
V_{GM}	Peak Gate Voltage		10	V
V_{ISO}	Isolation Breakdown Voltage (R.M.S.)	A.C. 1 minute	1500	V
T_j	Operating Junction Temperature		-40 to +125	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^\circ\text{C}$
	Mass		2	g

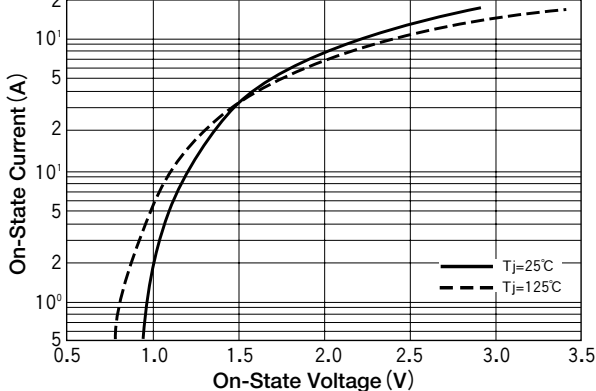
Electrical Characteristics

Symbol	Item	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
I_{DRM}	Reptitive Peak Off-State Current	$V_D=V_{\text{DRM}}$, Single phase, half wave, $T_j=125^\circ\text{C}$			2	mA
V_{TM}	Peak On-State Voltage	$I_T=25\text{A}$, Inst. measurement			1.4	V
I_{GT1}^+	Gate Trigger Current	$V_D=6\text{V}$, $R_L=10\Omega$	1		30	mA
I_{GT1}^-			2		30	
I_{GT3}^+			3		—	
I_{GT3}^-			4		30	
V_{GT1}^+	Gate Trigger Voltage	$V_D=6\text{V}$, $R_L=10\Omega$	1		1.5	V
V_{GT1}^-			2		1.5	
V_{GT3}^+			3		—	
V_{GT3}^-			4		1.5	
V_{GD}	Non-Trigger Gate Voltage	$T_j=125^\circ\text{C}$, $V_D=\frac{1}{2}V_{\text{DRM}}$	0.2			V
$(\text{dv}/\text{dt})_c$	Critical Rate of Rise off-State Voltage at commutation	$T_j=125^\circ\text{C}$, $(\text{di}/\text{dt})_c=-8\text{A}/\text{ms}$, $V_D=\frac{2}{3}V_{\text{DRM}}$	10			$\text{V}/\mu\text{s}$
I_{H}	Holding Current			25		mA
$R_{\text{th(j-c)}}$	Thermal Impedance	Junction to case			3.0	$^\circ\text{C}/\text{W}$

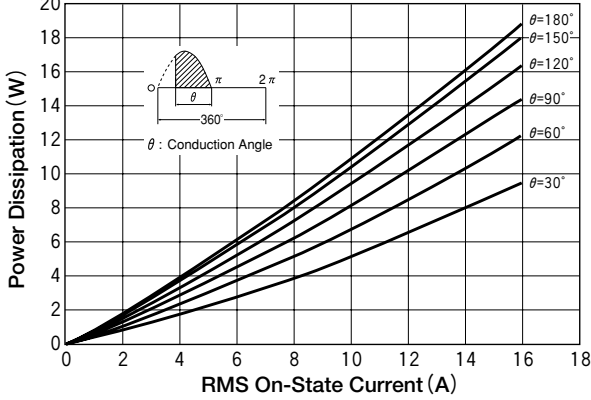
Gate Characteristics



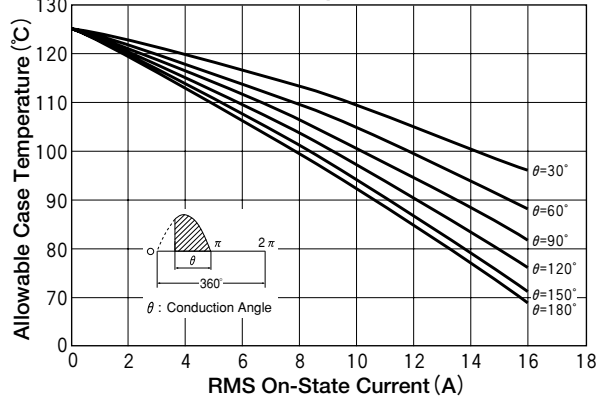
On-State Voltage



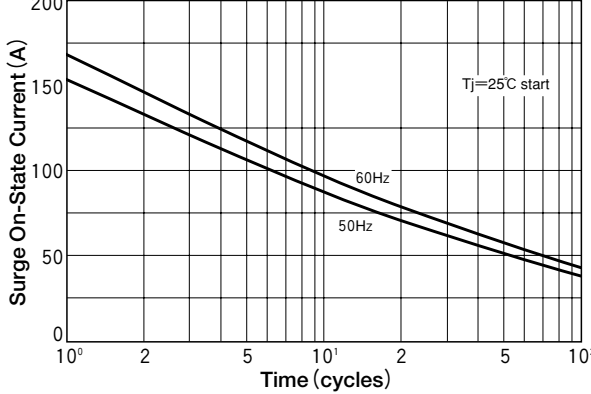
On State Current vs. Maximum Power Dissipation



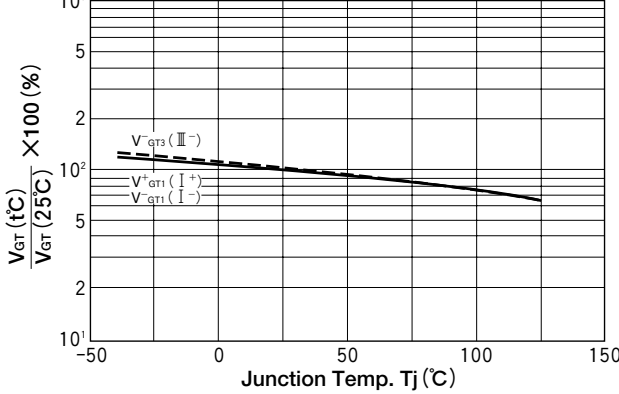
On State Current vs. Allowable Case Temperature



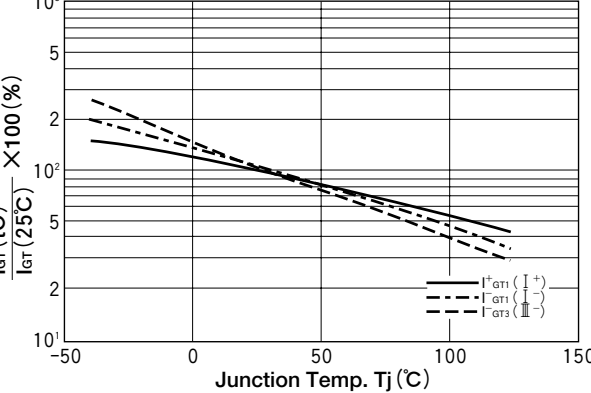
Surge On-State Current Rating (Non-Repetitive)



Gate trigger voltage vs. Junction temperature



Gate trigger current vs. Junction temperature



Transient Thermal Impedance

